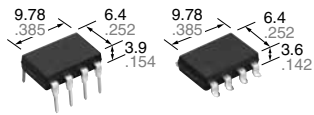




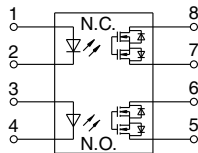
Both N.O. and N.C. contacts incorporated in a compact DIP8-pin Reinforced insulation

**PhotoMOS®
GE 1 Form A & 1 Form B
(AQW61○EH)**



(Height includes standoff)

mm inch



RoHS compliant

FEATURES

- 60V type couples high capacity (0.5A) with low on-resistance (Typ. 1Ω).**
- Reinforced insulation 5,000 V**
More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).
- Approx. 1/2 the space compared with the mounting area of a set of 1 Form A and 1 Form B PhotoMOS**
- Applicable for 1 Form A and 1 Form B use as well as two independent 1 Form A and 1 Form B use**
- Controls low-level analog signals**
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

6. High sensitivity and high speed response

Can control max. 0.14 A load current with 5 mA input current. Fast operation speed of Typ. 0.5 ms [N.O.] (AQW610EH).

7. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- Measuring instruments
- Security equipment
- Modem
- Telephone equipment
- Electricity, plant equipment
- Sensing equipment

TYPES

| | I/O isolation voltage | Output rating* | | Package | Part No. | | | | Packing quantity | |
|----------------|-----------------------|----------------|--------------|----------|-----------------------|------------------------|----------------------------------|----------------------------------|--|---------------|
| | | | | | Through hole terminal | Surface-mount terminal | | | | |
| | | Load voltage | Load current | | | Tube packing style | | Tape and reel packing style | | |
| | | | | | | | Picked from the 1/2/3/4-pin side | Picked from the 5/6/7/8-pin side | Tube | Tape and reel |
| AC/DC dual use | Reinforced 5,000 Vrms | 60 V | 500 mA | DIP8-pin | AQW612EH | AQW612EHA | AQW612EHAX | AQW612EHAZ | 1 tube contains: 50 pcs. 1 batch contains: 500 pcs. | 1,000 pcs. |
| | | 350 V | 120 mA | | AQW610EH | AQW610EHA | AQW610EHAX | AQW610EHAZ | | |
| | | 400 V | 100 mA | | AQW614EH | AQW614EHA | AQW614EHAX | AQW614EHAZ | | |

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

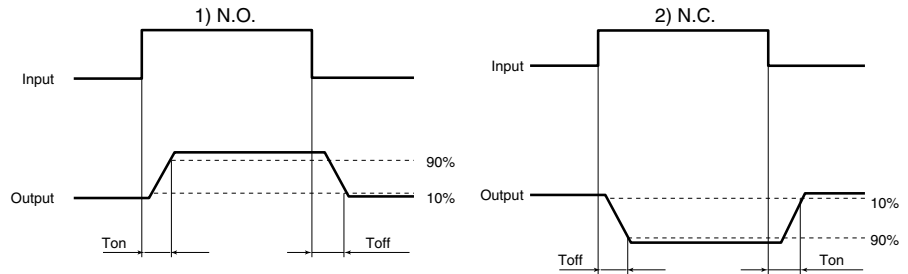
| Item | | Symbol | AQW612EH(A) | AQW610EH(A) | AQW614EH(A) | Remarks |
|-------------------------|-------------------------|-------------------|-----------------------------|-----------------|----------------|--|
| Input | LED forward current | I _F | 50 mA | | | |
| | LED reverse voltage | V _R | 5 V | | | |
| | Peak forward current | I _{FP} | 1 A | | | f = 100 Hz, Duty factor = 0.1% |
| | Power dissipation | P _{in} | 75 mW | | | |
| Output | Load voltage (peak AC) | V _L | 60 V | 350 V | 400 V | |
| | Continuous load current | I _L | 0.5 A (0.6 A) | 0.12 A (0.14 A) | 0.1 A (0.13 A) | Peak AC, DC (): in case of using only 1a or 1b, 1 channel |
| | Peak load current | I _{peak} | 1.5 A | 0.36 A | 0.3 A | 100 ms (1 shot), V _L = DC |
| | Power dissipation | P _{out} | 800 mW | | | |
| Total power dissipation | | P _T | 850 mW | | | |
| I/O isolation voltage | | V _{iso} | 5,000 Vrms | | | |
| Ambient temperature | Operating | T _{opr} | -40 to +85°C -40 to +185°F | | | (Non-icing at low temperatures) |
| | Storage | T _{stg} | -40 to +100°C -40 to +212°F | | | |

GE 1 Form A & 1 Form B (AQW610EH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

| Item | | Symbol | AQW612EH(A) | AQW610EH(A) | AQW614EH(A) | Condition |
|----------------------------------|---------------------------|--|---------------------------------|--------------------------------|--------------------------------|---|
| Input | LED operate current | Typical | 1.4 mA | | | I _L =Max. |
| | | Maximum | 3.0 mA | | | |
| | LED reverse current | Minimum | 0.4 mA | | | I _L =Max. |
| | | Typical | 1.3 mA | | | |
| LED dropout voltage | Typical | 1.25 (1.14 V at I _F = 5 mA) | | | I _F =50 mA | |
| | Maximum | 1.5 V | | | | |
| Output | On resistance | Typical | 1Ω | 18Ω | 26Ω | I _F =5mA (N.O.) I _F = 0mA (N.C.) I _L = Max. Within 1 s |
| | | Maximum | 2.5Ω | 25Ω | 35Ω | |
| | Off state leakage current | Maximum | 1μA (N.O.), 10μA (N.C.) | | | I _F =0 mA (N.O.) I _F = 5 mA (N.C.) V _L = Max. |
| Transfer characteristics | Operate time* | Typical | 1.0 ms (N.O.) 3.0 ms (N.C.) | 0.5 ms (N.O.) 1.0 ms (N.C.) | 0.5 ms (N.O.) 0.8 ms (N.C.) | I _F = 0 mA → 5 mA I _L = Max. |
| | | Maximum | 4.0 ms (N.O.) 10.0 ms (N.C.) | 3.0 ms | | |
| | Reverse time* | Typical | 0.05ms (N.O.), 0.2ms (N.C.) | 0.08ms (N.O.), 0.3ms (N.C.) | 0.08ms (N.O.), 0.2ms (N.C.) | I _F = 5 mA → 0 mA I _L = Max. |
| | | Maximum | 1.0ms | | | |
| | I/O capacitance | Typical | 0.8 pF | | | f = 1MHz V _B = 0 V |
| | | Maximum | 1.5 pF | | | |
| Initial I/O isolation resistance | Minimum | R _{iso} | 1,000MΩ | | | 500 V DC |

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

| Item | Symbol | Number of used channels | Min. | Max. | Unit |
|-------------|-------------------------|-------------------------|------|--------------|------|
| LED current | I _F | | 5 | 30 | mA |
| AQW612EH(A) | Load voltage (Peak AC) | | — | 48 | V |
| | Continuous load current | 1ch 2ch | — | 0.6 0.5 | A |
| AQW610EH(A) | Load voltage (Peak AC) | | — | 280 | V |
| | Continuous load current | 1ch 2ch | — | 0.14 0.12 | A |
| AQW614EH(A) | Load voltage (Peak AC) | | — | 320 | V |
| | Continuous load current | 1ch 2ch | — | 0.13 0.1 | A |

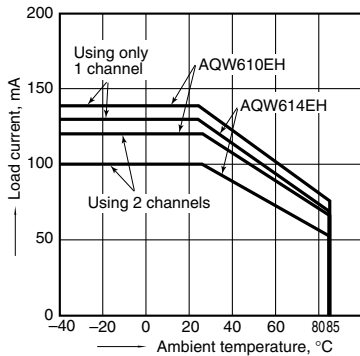
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

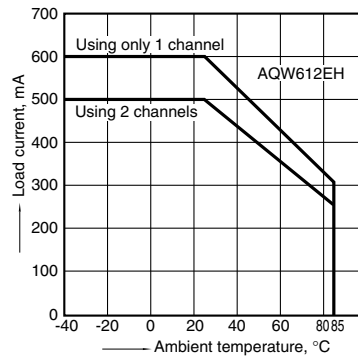
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C
-40 to +185°F



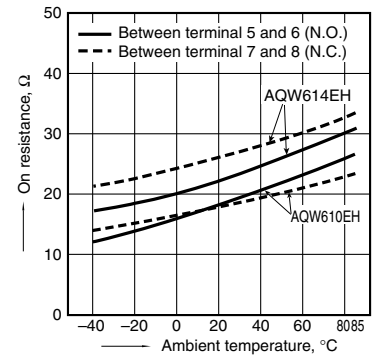
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C
-40 to +185°F



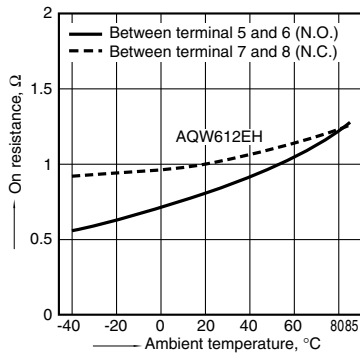
2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Load voltage; Max. (DC)
Continuous load current: Max. (DC)



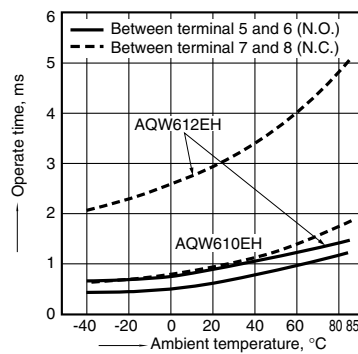
2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Load voltage; Max. (DC)
Continuous load current: Max. (DC)



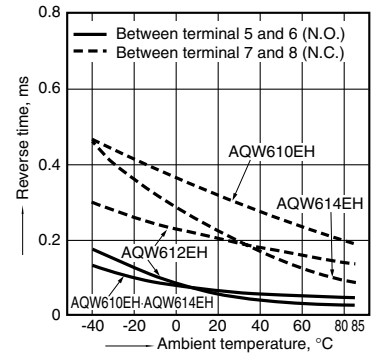
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage; Max. (DC);
Continuous load current: Max. (DC)



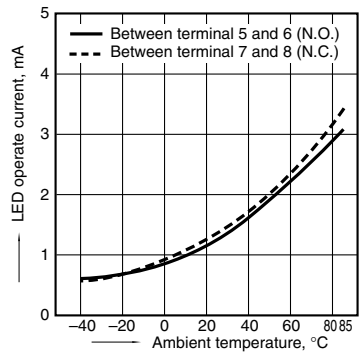
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage; Max. (DC);
Continuous load current: Max. (DC)



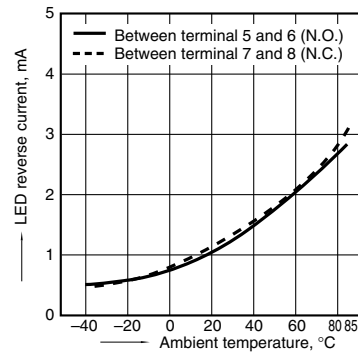
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage; Max. (DC);
Continuous load current: Max. (DC)



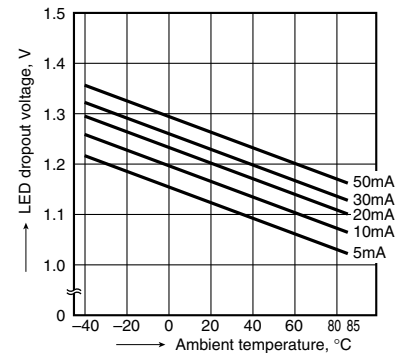
6. LED reverse current vs. ambient temperature characteristics

Sample: All types; Load voltage; Max. (DC);
Continuous load current: Max. (DC)



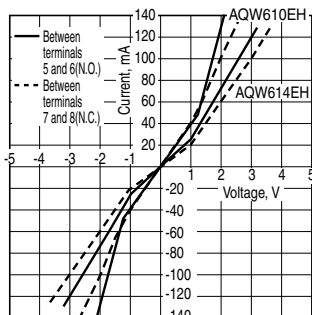
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
LED current: 5 to 50 mA



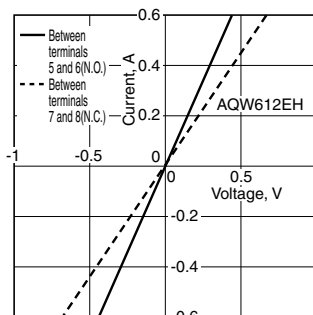
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



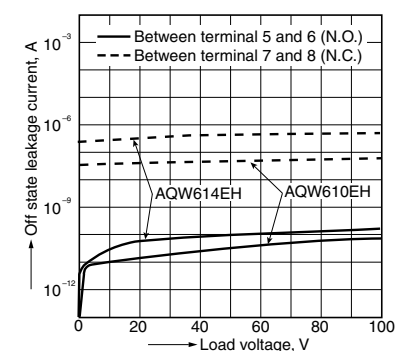
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



9-(1). Off state leakage current vs. load voltage characteristics

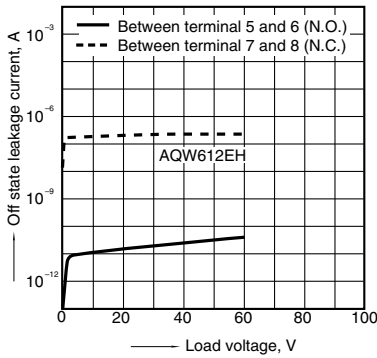
Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



GE 1 Form A & 1 Form B (AQW610EH)

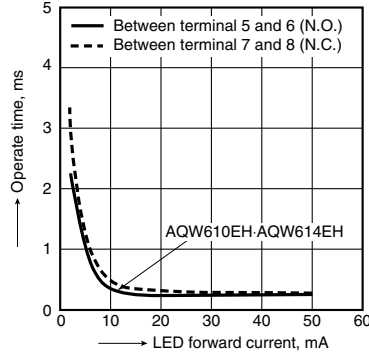
9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



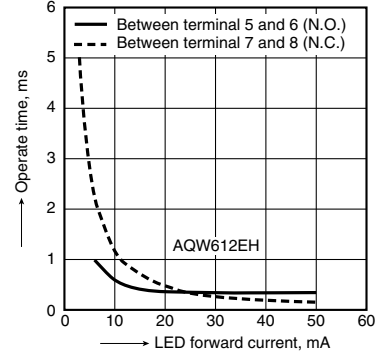
10-(1). Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



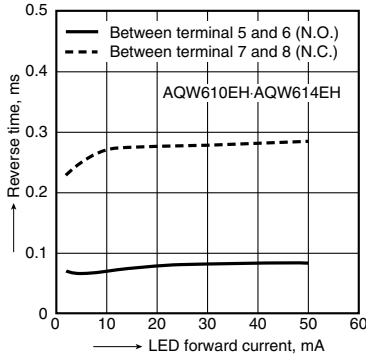
10-(2). Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



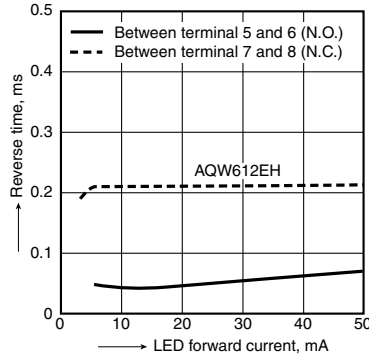
11-(1). Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



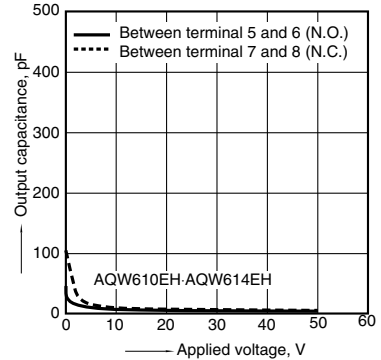
11-(2). Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



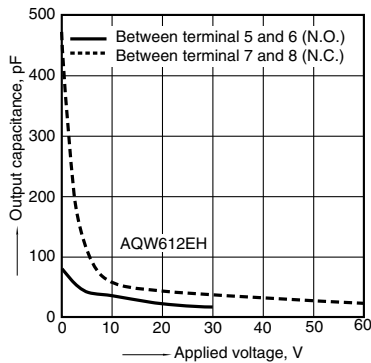
12-(1). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



12-(2). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



"PhotoMOS®", "PhotoMOS" and "PHOTOMOS" are registered trademarks of Panasonic Corporation.

*Recognized in Japan, the United States, all member states of European Union and other countries.

Please contact

Panasonic Corporation

Electromechanical Control Business Division

■ 1006, Oaza Kadoma, Kadoma-shi, Osaka 571-8506, Japan
industrial.panasonic.com/ac/e/

Panasonic®

©Panasonic Corporation 2017